MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

# **TPC8089-H**

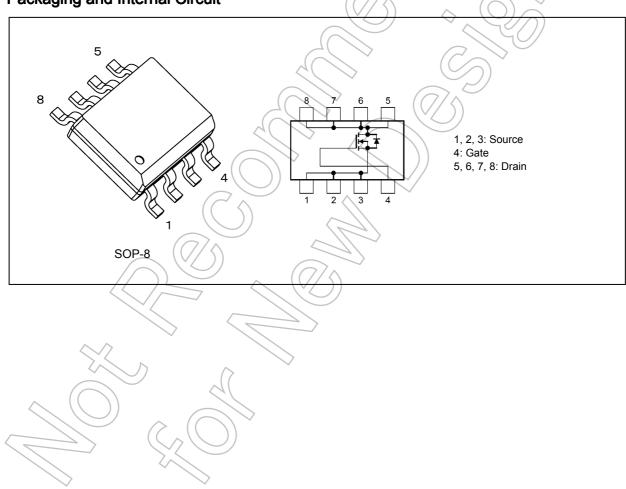
### 1. Applications

- Switching Voltage Regulators
- Motor Drivers
- DC-DC Converters

#### 2. Features

- (1) High-speed switching
- (2) Small gate charge:  $Q_{SW} = 3.6 \text{ nC}$  (typ.)
- (3) Low drain-source on-resistance:  $R_{DS(ON)} = 28 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 4.5 \text{ V})$
- (4) Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) ( $V_{DS}$  = 40 V)
- (5) Enhancement mode:  $V_{th} = 1.3$  to 2.3 V ( $V_{DS} = 10$  V,  $I_D = 0.1$  mA)

## 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25$ °C unless otherwise specified)

Charae	cteristics		Symbol	Rating	Unit
Drain-source voltage			V <sub>DSS</sub>	40	V
Gate-source voltage			V <sub>GSS</sub>	±20	
Drain current (DC)		(Note 1)	I <sub>D</sub>	7.2	A
Drain current (pulsed)		(Note 1)	I <sub>DP</sub>	28.8	
Power dissipation	(t = 10 s)	(Note 2)	PD	1.9	W
Power dissipation	(t = 10 s)	(Note 3)	PD	1.0	W
Single-pulse avalanche energy		(Note 4)	EAS	33	mJ
Avalanche current		4	I <sub>AR</sub>	) 7.2	A
Channel temperature			Tch	150	°C
Storage temperature				-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

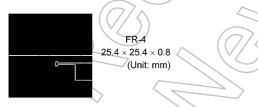
Characteristics		$\searrow$ (0/3	Symbol	Max	Unit
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 2)	R <sub>th(ch-a)</sub>	65.7	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R <sub>th(ch-a)</sub>	125	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4:  $V_{DD}$  = 32 V,  $T_{ch}$  = 25 °C (initial), L = 0.5 mH,  $I_{AR}$  = 7.2 A



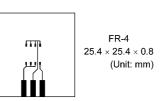


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

#### 6. Electrical Characteristics

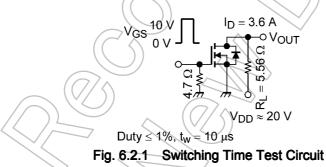
### 6.1. Static Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	_	—	±0.1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V	$\langle \rangle$	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	40		—	V
Drain-source breakdown voltage (Note 5)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	23	$\left  \right\rangle$	_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.1 mA	1.3	2_	2.3	
Drain-source on-resistance	R <sub>DS(ON)</sub>	$V_{GS}$ = 4.5 V, I <sub>D</sub> = 3.6 A	7	28	36	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.6 A	$\subseteq$	24	32	

Note 5: If a reverse bias is applied between gate and source, this device enters V<sub>(BR)DSX</sub> mode. Note that the drainsource breakdown voltage is lowered in this mode.

## 6.2. Dynamic Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 1 MHz		850	) —	pF
Reverse transfer capacitance	C <sub>rss</sub>		$\mathcal{A}$	40		
Output capacitance	C <sub>oss</sub>		$\sim$	145	_	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 5 MHz	()	3.8	4.9	Ω
Switching time (rise time)	tr	See Figure 6.2.1.	$\sim$	2.0	_	ns
Switching time (turn-on time)	t <sub>on</sub>		)) —	7.0	_	
Switching time (fall time)	t <sub>f</sub>		_	2.3	_	
Switching time (turn-off time)	t <sub>off</sub>		_	17	_	



## 6.3. Gate Charge Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD} \approx 32$ V, $V_{GS}$ = 10 V, $I_D$ = 7.2 A	_	14	_	nC
gate-drain)		$V_{DD} \approx 32$ V, $V_{GS}$ = 5 V, $I_D$ = 7.2 A	_	7.2	_	
Gate-source charge 1	Q <sub>gs1</sub>	$V_{DD} \approx 32$ V, $V_{GS}$ = 10 V, $I_D$ = 7.2 A	—	2.6	_	
Gate-drain charge	Q <sub>gd</sub>		_	2.4	_	
Gate switch charge	Q <sub>SW</sub>		_	3.6	_	

## 6.4. Source-Drain Characteristics ( $T_a = 25$ °C unless otherwise specified)

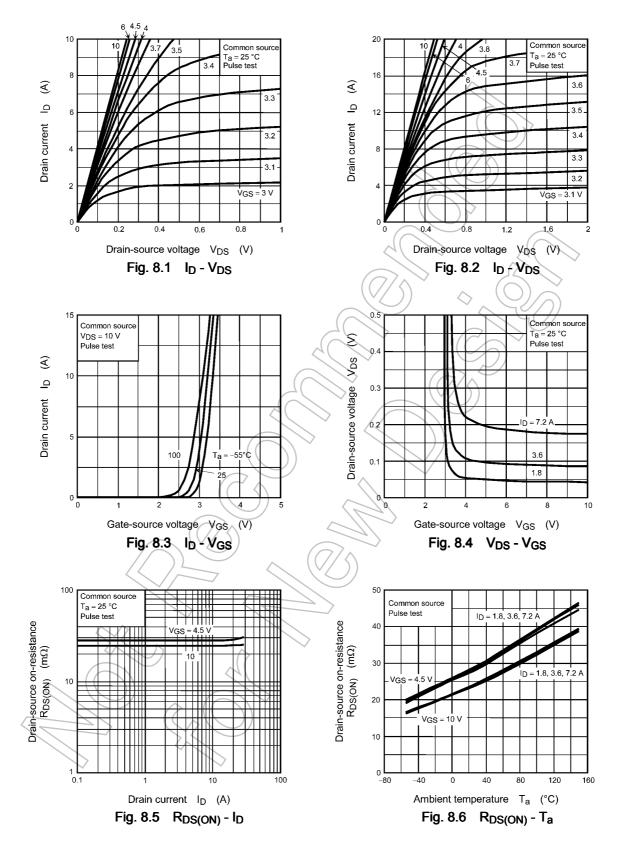
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed)	(Note 6)	I <sub>DRP</sub>		_	—	28.8	А
Diode forward voltage		$V_{DSF}$	I <sub>DR</sub> = 7.2 A, V <sub>GS</sub> = 0 V			-1.2	V

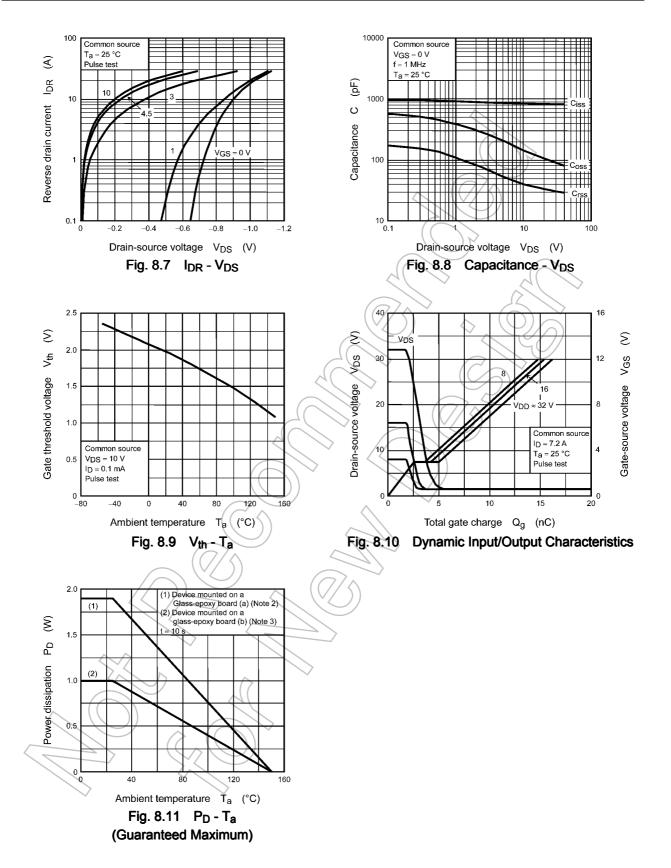
Note 6: Ensure that the channel temperature does not exceed 150 °C.

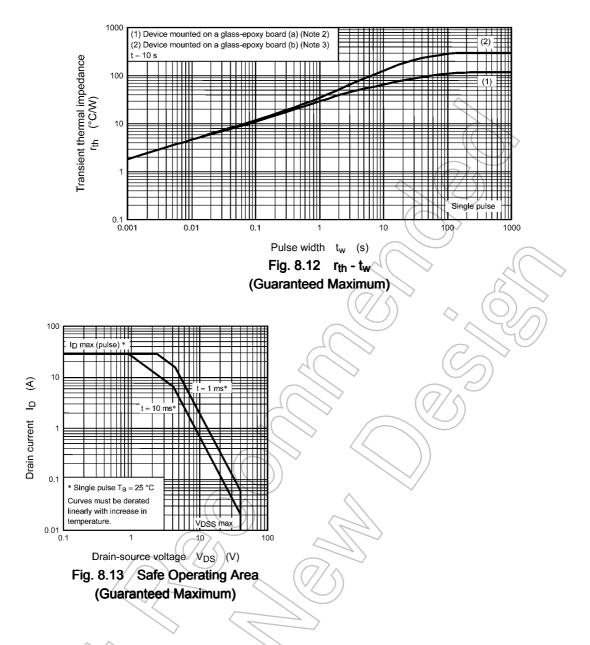
## TOSHIBA 7. Marking (Note)

	Part No. (or abbreviation code) H Defin #1 Fig. 7.1 Marking
Note:	A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

## 8. Characteristics Curves (Note)







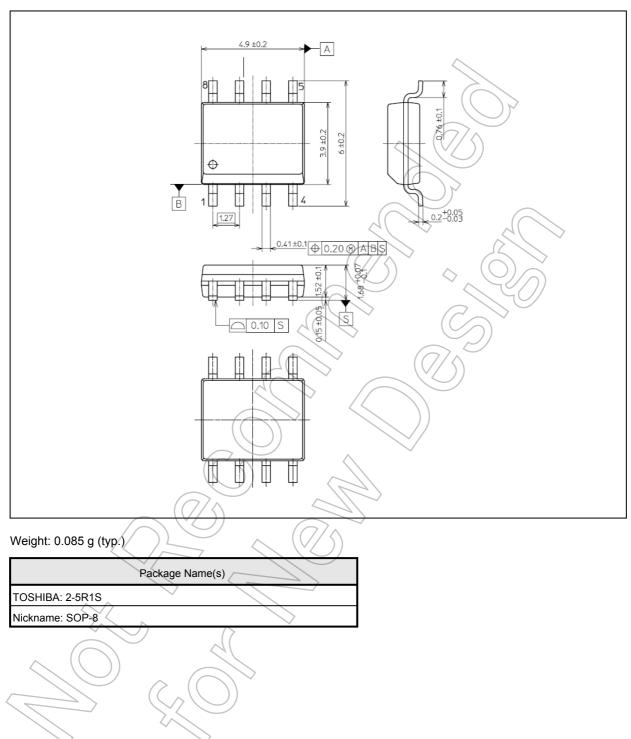
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## TPC8089-H

## Package Dimensions

Unit: mm



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